## Addressable peripheral drivers

## DESCRIPTION

The NE590/591 addressable peripheral drivers are high current latched drivers, similar in function to the 9334 address decoder. The device has eight Darlington power outputs, each capable of 250 mA load current. The outputs are turned on or off by respectively loading a logic high or logic low into the device data input. The required output is defined by a 3 -bit address. The device must be enabled by a CE input line. A common clear input, CLR, turns all outputs off when a logic low is applied.

The NE590 has eight open-collector Darlington outputs which sink current to ground. The device is packaged in a 16-pin plastic or Cerdip package.
The NE591 has eight open-emitter Darlington outputs which source current to an external load from a common collector line, $\mathrm{V}_{\mathrm{S}}$. This $\mathrm{V}_{\mathrm{S}}$ line need not necessarily be the same as the $5 \mathrm{~V} \mathrm{~V}_{\mathrm{CC}}$ supply. The device is packaged in an 18-pin plastic or Cerdip package.

FEATURES

- 8 high current outputs
- Low-loading bus compatible inputs
- Power-on clear ensures safe operation
- NE590 will operate in addressable or demultiplex mode
- Allows random (addressed) data entry
- Easily expandable
- NE590 is pin compatible with 54/74LS259


## APPLICATIONS

- Relay driver
- Indicator lamp driver
- Triac trigger
- LED display digit driver
- Stepper motor driver


## PIN CONFIGURATIONS



## ORDERING INFORMATION

| DESCRIPTION | TEMPERATURE RANGE | ORDER CODE | DWG \# |
| :--- | :---: | :---: | :---: |
| $16-$ Pin Plastic Dual In-Line Package (DIP) | 0 to $+70^{\circ} \mathrm{C}$ | 0 to $+70^{\circ} \mathrm{C}$ | NE590N |
| $18-$-Pin Plastic Dual In-Line Package (DIP) | 0406 C |  |  |

## PIN DESIGNATION

| $\begin{gathered} 590 \\ \text { PIN NO. } \end{gathered}$ | $\begin{gathered} 591 \\ \text { PIN NO. } \end{gathered}$ | SYMBOL | NAME \& FUNCTION |
| :---: | :---: | :---: | :---: |
| 1-3 | 2-4 | $\mathrm{A}_{0}-\mathrm{A}_{2}$ | A 3-bit binary address on these pins defines which of the 8 output latches is to receive the data. |
| $\begin{aligned} & 4-7, \\ & 9-12 \end{aligned}$ | $\begin{gathered} 5-8 \\ 11-14 \end{gathered}$ | $Q_{0}-Q_{7}$ | The 8 device outputs. The NE590 has open-collector Darlington outputs. The NE591 has open emit-ter-follower outputs. |
| 13 | 15 | D | The data input. When the chip is enabled, this data bit is transferred to the defined output such that: <br> "1" turns output switch "ON" <br> "0" turns output switch "OFF" |
|  |  |  | Thus in logic terms, the NE590 inverts data to the relevant output. The NE591 retains true data at the output. |
| 14 | 16 | CE | The chip enable. When this input is low, the output latches will accept data. When $\overline{C E}$ goes high, all outputs will retain their existing state regardless of address or data input conditions. |
| 15 | 17 | CLR | The clear input. When CLR goes low all output switches are turned "OFF". On the NE590, a high data input will override the clear function on the addressed latch. On the NE591, CLR low will override any other condition. |
| - | 1 | $\overline{\mathrm{CS}}$ | The chip select input provides for an additional level of address decoding. |
| - | 10 | $\mathrm{V}_{\mathrm{S}}$ | The $\mathrm{V}_{\mathrm{S}}$ line provides the power to all 8 output devices. It is connected to the collectors of all 8 output transistors. This pin may be connected to the $\mathrm{V}_{\mathrm{CC}}$ or another supply. |

## BLOCK DIAGRAM



## TRUTH TABLE (NE590)



NOTES:
$\mathrm{X}=$ Don't care condition
$Q_{N-1}=$ Previous output state
L=Low voltage level/"OFF" output state
H=High voltage level/"ON" output state
TRUTH TABLE (NE591)

\begin{tabular}{|c|c|c|c|c|c|c|c|c|c|c|c|c|c|c|c|}
\hline \multicolumn{7}{|c|}{INPUTS} \& \multicolumn{8}{|c|}{OUTPUTS} \& MODE <br>
\hline $$
\begin{gathered}
\overline{C L} \\
\mathrm{R}
\end{gathered}
$$ \& $$
\overline{\mathbf{C}}
$$ \& $$
\overline{\mathbf{C}}
$$ \& D \& $$
\begin{aligned}
& \text { A } \\
& 0
\end{aligned}
$$ \& $$
\begin{gathered}
\text { A } \\
1
\end{gathered}
$$ \& \& Q \& Q
1 \& Q \& Q
3 \& Q \& Q
5 \& Q \& \& <br>
\hline L \& X \& X \& X \& X \& X \& X \& L \& L \& L \& L \& L \& L \& L \& \& Clear <br>
\hline H
H
H \& H
H
L \& H
L
H \& X
X
X
X \& X
X
X
X \& X \& $$
\begin{aligned}
& \mathrm{X} \\
& \mathrm{x} \\
& \mathrm{X}
\end{aligned}
$$ \& $$
\begin{aligned}
& \mathrm{Q}_{\mathrm{N}-} \\
& \mathrm{Q}_{\mathrm{N}-} \\
& \mathrm{Q}_{\mathrm{N}}
\end{aligned}
$$ \&  \& \& \& \&  \&  \& \& Memory <br>
\hline H \& L
L
L
L
L
L \& L
L
L
L
L \& H
L
H
L
H \& L
L
H
H
H
H \& $$
\begin{gathered}
\hline \mathrm{L} \\
\mathrm{~L} \\
\mathrm{~L} \\
\mathrm{~L} \\
\mathrm{H} \\
\mathrm{H}
\end{gathered}
$$ \& $$
\begin{gathered}
\hline \mathrm{L} \\
\mathrm{~L} \\
\mathrm{~L} \\
\mathrm{~L} \\
\mathrm{H} \\
\mathrm{H}
\end{gathered}
$$ \& L
H

$\mathrm{Q}_{\mathrm{N}}$
$\mathrm{Q}_{\mathrm{N}-1}$
$\mathrm{Q}_{\mathrm{N}}$

$\mathrm{Q}_{\mathrm{N}-1}$ \& $Q_{N}$ \&  \&  \&  \&  \& \& \& Addressable Latch <br>
\hline
\end{tabular}

NOTES:
X=Don't care condition
$\mathrm{Q}_{\mathrm{N}-1}=$ Previous output state
L=Low voltage level/"OFF" output state
H=High voltage level/"ON" output state

## ABSOLUTE MAXIMUM RATINGS

| SYMBOL | PARAMETER | RATING | UNIT |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CC }}$ | Supply voltage | -0.5 to +7 | V |
| $\mathrm{V}_{\text {IN }}$ | Input voltage | -0.5 to +15 | V |
| $\mathrm{V}_{\text {OUT }}$ | Output voltage NE590 NE591 | $\begin{gathered} 0 \text { to }+7 \\ 0 \text { to } \mathrm{V}_{\mathrm{CC}} \end{gathered}$ | V |
| $\mathrm{V}_{\mathrm{S}}$ | Source bus voltage NE591 only | -0.5 to +7 | V |
| $\mathrm{V}_{\mathrm{S}}-\mathrm{V}_{\mathrm{CC}}$ | Source/supply differential voltage NE591 only | -5 to +2 | V |
| lout | Output current <br> Each output <br> All outputs | $\begin{gathered} 300 \\ 1000 \end{gathered}$ | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Maximum power dissipation $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ (still air) <br> NE590 ${ }^{1}$ N package <br> NE591 ${ }^{2}$ N package | $\begin{aligned} & 1450 \\ & 1690 \end{aligned}$ | mW |
| $\mathrm{T}_{\mathrm{A}}$ | Ambient temperature range | 0 to +70 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Junction temperature | 165 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {STG }}$ | Storage temperature range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {SOLD }}$ | Lead soldering temperature ( $10 \mathrm{sec} \max$ ) | 300 | ${ }^{\circ} \mathrm{C}$ |

NOTES:

1. Derate above $25^{\circ} \mathrm{C}$ at the following rates: N package at $11.6 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$
2. Derate above $25^{\circ} \mathrm{C}$ at the following rates: N package at $13.5 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$

## DC ELECTRICAL CHARACTERISTICS

$\mathrm{V}_{\mathrm{CC}}=4.75$ to $5.25 \mathrm{~V}, 0^{\circ} \mathrm{C} \geq \mathrm{T}_{\mathrm{A}} \leq 70^{\circ} \mathrm{C}$ unless otherwise specified. ${ }^{1,2}$

| SYMBOL | PARAMETER | TEST CONDITIONS | LIMITS |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max |  |
| $\begin{aligned} & \mathrm{v}_{\mathrm{IH}} \\ & \mathrm{v}_{\mathrm{IL}} \\ & \hline \end{aligned}$ | Input voltage <br> High <br> Low |  | 2.0 |  | 0.8 | V |
| $\begin{array}{\|l} \mathrm{v}_{\mathrm{OL}} \\ \mathrm{v}_{\mathrm{OH}} \\ \hline \end{array}$ | Output voltage <br> Low (NE590 only) <br> High (NE591 only) | $\begin{gathered} \mathrm{I}_{\mathrm{OL}}=250 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ \text { Over temperature } \\ \mathrm{l}_{\mathrm{OH}}=-250 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{S}}=5 \mathrm{~V} \\ \hline \end{gathered}$ | 2.9 | 1.0 | $\begin{aligned} & 1.3 \\ & 1.5 \end{aligned}$ | V |
| $\left\lvert\, \begin{aligned} & I_{\mathrm{IH}} \\ & I_{\mathrm{IL}} \end{aligned}\right.$ | Input current <br> High <br> Low <br> CE input <br> All other inputs | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.1 \\ & -25 \\ & -15 \end{aligned}$ | $\begin{aligned} & 10 \\ & -60 \\ & -50 \end{aligned}$ | $\mu \mathrm{A}$ |
| IOH | Leakage current | $\mathrm{V}_{\text {OUT }}=5.25 \mathrm{~V}$ |  | 10 | 250 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CCL}}$ | Supply current ${ }^{3}$ <br> All outputs low <br> NE590 <br> NE591 <br> All outputs high <br> NE590 <br> NE591 | $\mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  | $\begin{aligned} & 33 \\ & 15 \\ & 15 \\ & 30 \\ & \hline \end{aligned}$ | $\begin{aligned} & 50 \\ & 50 \\ & 50 \\ & 50 \\ & \hline \end{aligned}$ | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Power dissipation | No output load |  |  | 350 | mW |

NOTES:

1. All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
2. For the NE591 $\mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{CC}}$ in all tests.
3. Supply current for the NE591 is measured with no output load.

## SWITCHING CHARACTERISTICS

$\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| SYMBOL | PARAMETER | TO | FROM | NE590 |  |  | NE591 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Typ | Max |  |
| $\left\lvert\, \begin{array}{l\|l\|} \hline \text { tPLH } \\ \mathrm{t}_{\text {PHL }} \end{array}\right.$ | Propagation delay time Low-to-High ${ }^{1}$ High-to-Low ${ }^{1}$ | Output | CE |  | $\begin{gathered} 65 \\ 115 \end{gathered}$ | $\begin{aligned} & 150 \\ & 230 \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 70 \end{aligned}$ | $\begin{gathered} 80 \\ 120 \end{gathered}$ | ns |
| $\begin{array}{\|l\|} \hline \mathrm{t}_{\mathrm{PLH}} \\ \mathrm{t}_{\mathrm{PHL}} \\ \hline \end{array}$ | Low-to-High ${ }^{2}$ High-to-Low ${ }^{2}$ | Output | Data |  | $\begin{gathered} 65 \\ 120 \end{gathered}$ | $\begin{aligned} & 130 \\ & 240 \end{aligned}$ |  | $\begin{aligned} & 45 \\ & 65 \end{aligned}$ | $\begin{gathered} \hline 70 \\ 100 \end{gathered}$ | ns |
| $\begin{array}{\|l\|} \hline \begin{array}{l} \text { tPLH } \\ t_{\text {PHL }} \end{array} \\ \hline \end{array}$ | Low-to-High ${ }^{3}$ High-to-Low ${ }^{3}$ | Output | Address |  | $\begin{aligned} & 100 \\ & 130 \end{aligned}$ | $\begin{aligned} & 200 \\ & 260 \end{aligned}$ |  | $\begin{aligned} & 45 \\ & 75 \end{aligned}$ | $\begin{gathered} \hline 80 \\ 140 \end{gathered}$ | ns |
| $\begin{array}{\|l\|l\|} \hline \text { tPLH } \\ \mathrm{t}_{\mathrm{PHL}} \end{array}$ | Low-to-High ${ }^{4}$ High-to-Low ${ }^{4}$ | Output | $\overline{\mathrm{CLR}}$ |  | 65 | 130 |  | 45 | 140 | ns |
| $\begin{aligned} & \text { tPLH } \\ & \text { tPHL } \\ & \hline \end{aligned}$ | Low-to-High ${ }^{1}$ High-to-Low ${ }^{1}$ | Output | $\overline{\text { CS }}$ |  |  |  |  | $\begin{aligned} & 40 \\ & 70 \end{aligned}$ | $\begin{gathered} 80 \\ 120 \end{gathered}$ | ns |
| Switching setup requirements |  |  |  |  |  |  |  |  |  |  |
| $\begin{aligned} & \mathrm{t}_{\mathrm{S}(\mathrm{H})} \\ & \mathrm{t}_{\mathrm{S}(\mathrm{~L})} \end{aligned}$ |  | Chip enable Chip enable | High data <br> Low data | $\begin{aligned} & 210 \\ & 210 \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & 100 \\ & 100 \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & \hline \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{S}(\mathrm{A})}$ |  | Chip enable | Address | 30 |  |  | 30 |  |  | ns |
| $\begin{aligned} & \mathrm{t}_{\mathrm{H}(\mathrm{H})} \\ & \mathrm{t}_{\mathrm{H}(\mathrm{~L})} \end{aligned}$ |  | Chip enable Chip enable | High data Low data | $\begin{aligned} & 40 \\ & 30 \end{aligned}$ |  |  | $\begin{aligned} & \hline 10 \\ & 10 \end{aligned}$ |  |  | $\begin{aligned} & \hline \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{S}(\mathrm{CS})}$ |  | Chip enable | Low chip select |  |  |  | 100 |  |  | ns |
| tPW(E) | Chip enable pulse width ${ }^{1}$ |  |  | 120 |  |  | 120 |  |  | ns |

## NOTES:

1. See Turn-On and Turn-Off Delays, Enable to Output and Enable Pulse Width timing diagram.
2. See Turn-On and Turn-Off Delays, Data to Output timing diagram.
3. See Turn-On and Turn-Off Delays, Address to Output timing diagram.
4. See Turn-Off Delay, Clear to Output timing diagram.
5. See Setup and Hold Time, Data to Enable timing diagram.
6. See Setup Time, Address to Enable timing diagram.

## FUNCTIONAL DESCRIPTION

These peripheral drivers have latched outputs which hold the input data until cleared. The NE590 has active-Low, open-collector outputs, while the NE591 has active-High, uncommitted (open) emitter outputs. All outputs are cleared when power is first applied.

## Addressable Latch Function

Any given output can be turned on or off by presenting the address of the output to be set or cleared to the three address pins, by holding the " $D$ " input High to turn on the selected input, or by holding it Low to turn off, holding the CLR input High, and bringing the CE input Low. Once an output is turned on or off, it will remain so until addressed again, or until all outputs are cleared by bringing the CLR, CE, and "D" inputs Low. For NE591, CS must be brought Low any time CE is Low if any outputs are to be changed.

## Demultiplexer Operation

By bringing the CLR and CE inputs Low and the "D" input High, the addressed output will remain on and all other outputs will be off. This condition will remain only as long as the output is addressed. For the NE591, the CS input must also be Low.

## High Current Outputs

The obvious advantage of these devices over the 9334 and N74LS259 (which provide a similar function) is the fact that the NE590 and NE591 are capable of output currents of 250 mA at each of their eight outputs. It should be noted, however, that the load power dissipation would be over 2.5 W if all 8 outputs were to carry their full rated load current at one time. Since the total power
dissipation is limited by the package to 1 W , and since the power dissipation due to supply current is 0.25 W , the total load power dissipation by the device is limited to 0.75 W , and decreases as ambient temperature rises.

The maximum die junction temperature must be limited to $165^{\circ} \mathrm{C}$, and the temperature rise above ambient and the junction temperature are defined as:

$$
\begin{aligned}
& \mathrm{t}_{\mathrm{R}}=\theta_{\mathrm{JA}} \times \mathrm{P} \\
& \mathrm{t}_{\mathrm{J}}=\mathrm{t}_{\mathrm{A}}+\mathrm{t}_{\mathrm{R}}
\end{aligned}
$$

## where

$\theta_{\mathrm{JA}}$ is die junction to ambient thermal resistance.
$P_{D}$ is total power dissipation $t_{R}$ is junction temperature rise above ambient $\mathrm{t}_{\mathrm{j}}$ is die junction temperature
$\mathrm{t}_{\mathrm{A}}$ is ambient (surrounding medium) temperature
For example, if we are using the NE590 in a plastic package in an application where the ambient temperature is never expected to rise above $50^{\circ} \mathrm{C}$, and the output current at the 8 outputs, when on, are $100,40,50,200,15,30,80$, and 10 mA , we find from the graph of output voltage vs load current that the output voltages are expected to be about $0.92,0.75,0.78,1.04,0.5,0.7,0.9$, and 0.4 V , respectively. Total device power due to these loads is found to be 473.5 mW . Adding the 250 mW due to the power supply brings total device power dissipation to 723.5 mW . The thermal resistances are $83^{\circ} \mathrm{C}$ per W for plastic packages and $100^{\circ} \mathrm{C}$ per W for Cerdips. Using the equations above we find:

Plastic $\mathrm{t}_{\mathrm{R}}=83 \times 0.7235=60^{\circ} \mathrm{C}$
Plastic $\mathrm{t}_{\mathrm{J}}=50+60=100^{\circ} \mathrm{C}$
Cerdip $\mathrm{t}_{\mathrm{R}}=100 \times 0.7235=72.40^{\circ} \mathrm{C}$
Cerdip $\mathrm{t}_{\mathrm{J}}=50+72.4=122.4^{\circ} \mathrm{C}$

Thus we find that $\mathrm{t}_{\mathrm{J}}$ for either package is below the $165^{\circ} \mathrm{C}$ maximum and either package could be used in this application. The graphs of total load power vs ambient temperature would also give us this same information, although interpreting the graphs would not yield the same accuracy.

## TYPICAL PERFORMANCE CHARACTERISTICS



Output Voltage vs Load Current (NE590)


Total Load Power vs Temperature
(NE590)


Output Voltage Drop vs Load Current (NE591)


Total Load Power vs Temperature (NE591)

TIMING DIAGRAMS


Turn-On and Turn-Off Delays, Enable-to-Output and Enable Pulse Width


NOTE:
Other inputs $C E=L, C L R=L, D=H$
Turn-On and Turn-Off Delays, Address-to-Output

## NOTE:

Other inputs $\overline{\mathrm{CLR}}=\mathrm{H}, \mathrm{CS}=\mathrm{L}$
Set-Up Time, Address-to-Enable


NOTE:
Other inputs $\overline{C E} \overline{C S}=L, \overline{C L R}=H, A=$ Stable
Turn-On and Turn-Off Delays, Data-to-Output


NOTE:
Other inputs $\overline{C S}=\mathrm{H}, \mathrm{CE}=\mathrm{H}$
Turn-On and Turn-Off Delays, Clear-to-Output


## NOTE:

Other inputs $\overline{C L R}=\mathrm{H}, \overline{\mathrm{CS}}=\mathrm{L}, \mathrm{A}=$ Stable
Set-Up and Hold Time, Data-to-Enable

TYPICAL APPLICATIONS


NOTE:
$A_{0}, A_{1}, A_{2}$, and CS may be connected to the address bus if permitted by system design.
Turn-On and Turn-Off Delays, Address-to-Output
NE590 Driving Simple Loads


